SN74CBT16210 20-BIT FET BUS SWITCH

SCDS033C - APRIL 1997 - REVISED MAY 1998

- **5-**Ω Switch Connection Between Two Ports
- TTL-Compatible Input Levels
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages

description

The SN74CBT16210 provides 20 bits of high-speed TTL-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay.

The device is organized as a dual 10-bit bus switch with separate output-enable (\overline{OE}) inputs. It can be used as two 10-bit bus switches or as one 20-bit bus switch. When \overline{OE} is low, the associated 10-bit bus switch is on and port A is connected to port B. When \overline{OE} is high, the switch is open, and a high-impedance state exists between the ports.

The SN74CBT16210 is characterized for operation from -40° C to 85° C.

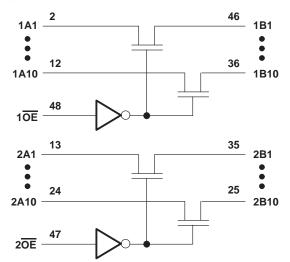
FUNCTION TABLE (each 10-bit bus switch)

INPUT OE	FUNCTION
L	A port = B port
н	Disconnect

logic diagram (positive logic)

DGG, DGV, OR DL PACKAGE (TOP VIEW)						
)					
2A8 22 27 2B8 2A9 23 26 2B9 2A10 24 25 2B10)					

NC - No internal connection





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V _{CC}		
Input voltage range, V _I (see Note 1)		-0.5 V to 7 V
Continuous channel current		128 mA
Input clamp current, I _{IK} (V _I < 0)		–50 mA
Package thermal impedance, θ_{JA} (see Note 2):	DGG package	89°C/W
	DGV package	93°C/W
	DL package	94°C/W
Storage temperature range, T _{stg}		°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 3)

		MIN	MAX	UNIT
VCC	Supply voltage	4	5.5	V
VIH	High-level control input voltage	2		V
VIL	Low-level control input voltage		0.8	V
Τ _Α	Operating free-air temperature	-40	85	°C
NOTES				

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST CONDITIONS		MIN	TYP‡	MAX	UNIT		
VIK		V _{CC} = 4.5 V,	I _I = -18 mA				-1.2	V	
Ц		$V_{CC} = 0 V,$	V _I = 5.5 V				10	μΑ	
		V _{CC} = 5.5 V,	$V_{I} = 5.5 \text{ V or GND}$				±1		
ICC		V _{CC} = 5.5 V,	I _O = 0,	$V_I = V_{CC}$ or GND			3	μA	
∆ICC§	Control inputs	V _{CC} = 5.5 V,	One input at 3.4 V,	Other inputs at V_{CC} or GND			2.5	mA	
Ci	Control inputs	VI = 3 V or 0				4.5		pF	
Cio(OFF)		V _O = 3 V or 0,	$\overline{OE} = V_{CC}$			5.5		pF	
ron¶		$V_{CC} = 4 V$, TYP at $V_{CC} = 4 V$	V _I = 2.4 V,	l _l = 15 mA		14	20		
			C = 4.5 V VI = 0	I _I = 64 mA		5	7	Ω	
		V _{CC} = 4.5 V		I _I = 30 mA		5	7		
		V _I = 2.4 V,	V _I = 2.4 V,	l _l = 15 mA		8	12		

[‡] All typical values are at V_{CC} = 5 V (unless otherwise noted), T_A = 25°C.

§ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

¶ Measured by the voltage drop between the A and B terminals at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) terminals.



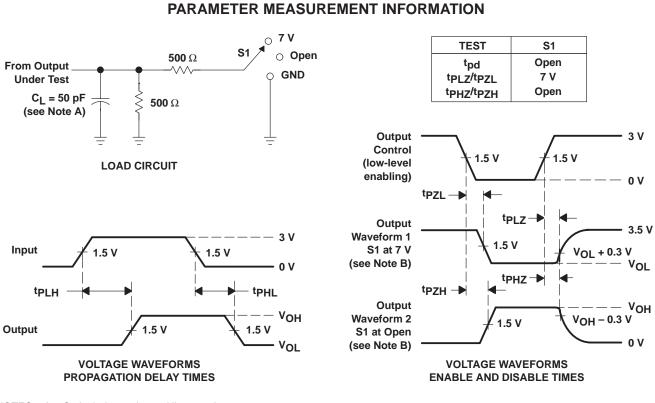
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switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 4 V	V _{CC} = 5 V ± 0.5 V		UNIT
			MIN MAX	MIN	MAX	
t _{pd} †	A or B	B or A	0.35		0.25	ns
ten	OE	A or B	9.3	3.3	8.6	ns
tdis	OE	A or B	7.1	2.8	7.9	ns

[†] The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f \leq 2.5 ns. t_f \leq 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tPLZ and tPHZ are the same as tdis.
- F. tPZL and tPZH are the same as ten.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



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